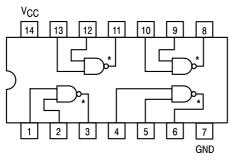
Quad 2-Input NAND Buffer



***OPEN COLLECTOR OUTPUTS**

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
VCC	Supply Voltage	4.75	5.0	5.25	V
TA	Operating Ambient Temperature Range	0	25	70	°C
VOH	Output Voltage – High			5.5	V
IOL	Output Current – Low			24	mA



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LOW POWER SCHOTTKY



PLASTIC N SUFFIX CASE 646



SOIC D SUFFIX CASE 751A



M SUFFIX CASE 965

ORDERING INFORMATION

Device	Package	Shipping	
SN74LS38N	14 Pin DIP	2000 Units/Box	
SN74LS38D	SOIC-14	55 Units/Rail	
SN74LS38DR2	SOIC-14	2500/Tape & Reel	
SN74LS38M	SOEIAJ-14	See Note 1	
SN74LS38MEL	SOEIAJ-14	See Note 1	

 For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

SN74LS38

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

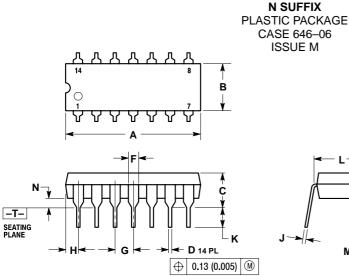
		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Co	onditions
VIH	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
VIL	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs	
VIK	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$	
ЮН	Output HIGH Current			250	μA	$V_{CC} = MIN, V_{OH} = MAX$	
			0.25	0.4	V		$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
				20	μA	V _{CC} = MAX, V _{IN} = 2.4 V	
Ίн	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
۱ _{IL}	Input LOW Current			-0.4	mA	$V_{CC} = MAX, V_{IN} = 0.4 V$	
ICC	Power Supply Current Total, Output HIGH			2.0	mA	A V _{CC} = MAX	
	Total, Output LOW			12			

AC CHARACTERISTICS (T_A = 25° C)

		Limits		Limits		
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
^t PLH	Turn-Off Delay, Input to Output		20	32	ns	V_{CC} = 5.0 V, R _L = 667 Ω
^t PHL	Turn-On Delay, Input to Output		18	28	ns	$C_L = 45 \text{ pF}$

SN74LS38

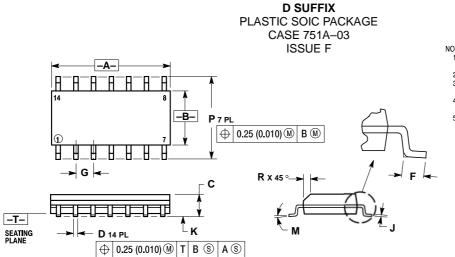
PACKAGE DIMENSIONS



м

NOTES NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION LTO CENTER OF LEADS WHEN FORMED PARALLEL. 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH. 5. ROUNDED CORNERS OPTIONAL.

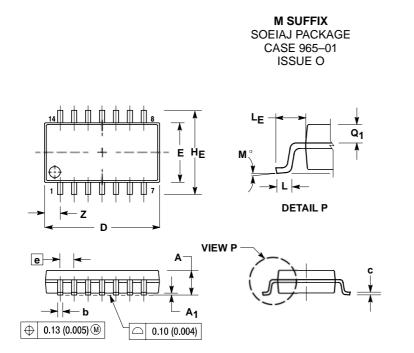
	INC	HES	MILLIN	IETERS
DIM	MIN	MIN MAX		MAX
Α	0.715	0.770	18.16	18.80
В	0.240	0.260	6.10	6.60
С	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100 BSC		2.54 BSC	
Н	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
Κ	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
М		10°		10 °
Ν	0.015	0.039	0.38	1.01



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE. 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	8.55	8.75	0.337	0.344	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27 BSC		0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0 °	7°	0 °	7°	
Р	5.80	6.20	0.228	0.244	
R	0.25	0.50	0.010	0.019	

PACKAGE DIMENSIONS



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

- 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR
- PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 4. TERMINAL NUMBERS ARE SHOWN FOR
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT, MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIN	IETERS	INCHES		
DIM	MIN MAX		MIN	MAX	
A		2.05		0.081	
A ₁	0.05	0.20	0.002	0.008	
Q	0.35	0.50	0.014	0.020	
C	0.18	0.27	0.007	0.011	
D	9.90	10.50	0.390	0.413	
E	5.10	5.45	0.201	0.215	
e	1.27	BSC	0.050	BSC	
HE	7.40	8.20	0.291	0.323	
0.50	0.50	0.85	0.020	0.033	
LE	1.10	1.50	0.043	0.059	
M	0 °	10 °	0 °	10 °	
Q1	0.70	0.90	0.028	0.035	
Z		1.42		0.056	

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